Surface Mount Schottky Power Rectifier

SMA Power Surface Mount Package

... employing the Schottky Barrier principle in a metal-to-silicon power rectifier. Features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency switching power supplies; free wheeling diodes and polarity protection diodes.

- Compact Package with J–Bend Leads Ideal for Automated Handling
- Highly Stable Oxide Passivated Junction
- Guardring for Over-Voltage Protection
- Optimized for Low Leakage Current

Mechanical Characteristics:

- Case: Molded Epoxy
- Epoxy Meets UL94, V_O at 1/8"
- Weight: 70 mg (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Polarity: Polarity Band Indicates Cathode Lead
- Available in 12 mm Tape, 5000 Units per 13 inch Reel
- Device Meets MSL1 Requirements
- ESD Ratings: Machine Model, C (>400 V)
 - Human Body Model, 3B (>8000 V)
- Marking: B1E2

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	20	V
Average Rectified Forward Current (At Rated V _R , T _C = 125°C)	Ι _Ο	1.0	A
Non–Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I _{FSM}	40	A
Storage Temperature	T _{stg}	-55 to +150	°C
Operating Junction Temperature	TJ	-55 to +150	°C
Voltage Rate of Change (Rated V _R , T _J = 25°C)	dv/dt	10,000	V/µs



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SCHOTTKY BARRIER RECTIFIER 1 AMPERE 20 VOLTS



MARKING DIAGRAM



SMA CASE 403D PLASTIC

B1E2 = Device Code

ORDERING INFORMATION

Device	Package	Shipping [†]	
MBRA120ET3	SMA	5000/Tape & Reel	

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

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THERMAL CHARACTERISTICS

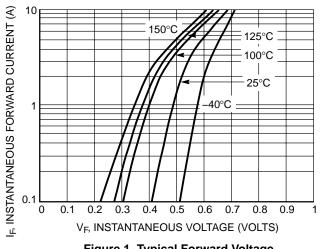
Characteristic	Symbol	5 mm x 5 mm (Note 2)	1 Inch x 1/2 inch (Note 3)	Unit
Thermal Resistance – Junction-to-Lead	R _{θJL}	34	20	°C/W
Thermal Resistance – Junction-to-Ambient	R _{θJA}	138	77	

ELECTRICAL CHARACTERISTICS

Maximum Instantaneous Forward Voltage (Note 1), See Figure 2	V _F	T _J = 25°C	T _J = 100°C	V
$(I_F = 0.1 \text{ A})$ $(I_F = 1.0 \text{ A})$ $(I_F = 2.0 \text{ A})$		0.455 0.530 0.595	0.360 0.455 0.540	
Maximum Instantaneous Reverse Current, See Figure 4	I _R	T _J = 25°C	T _J = 100°C	μΑ
$(V_R = 20 V)$ $(V_R = 10 V)$ $(V_R = 5.0 V)$		10 1.0 0.5	1600 500 300	

Pulse Test: Pulse Width \leq 250 µs, Duty Cycle \leq 2%. 1.

Mounted on a Pad Size of 5 mm x 5 mm, PC Board FR4 (2 pads).
Mounted on a Pad Size of 1 inch x 1/2 inch, PC Board FR4 (2 pads).





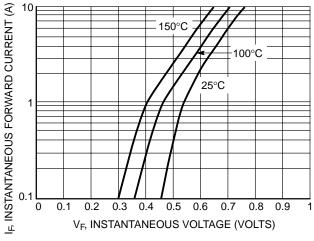
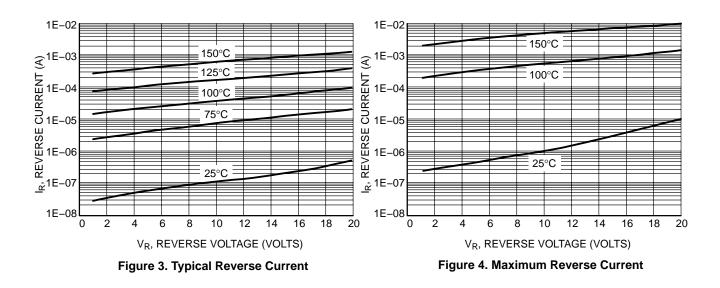
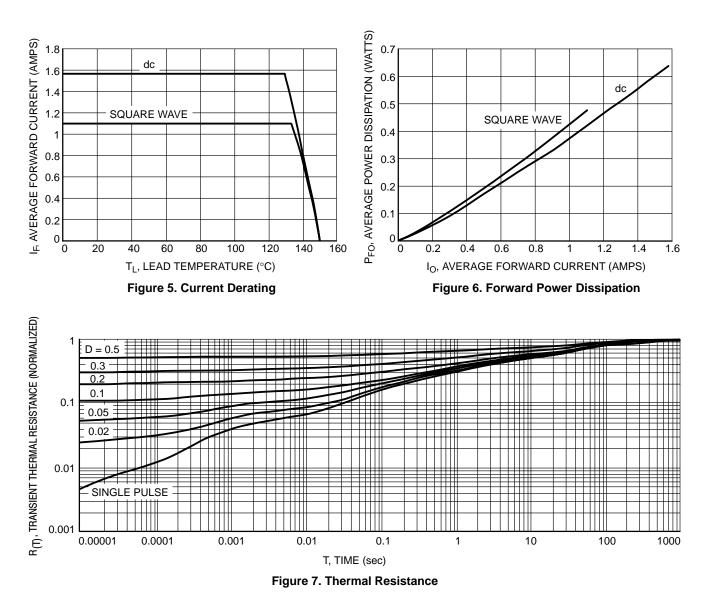


Figure 2. Maximum Forward Voltage





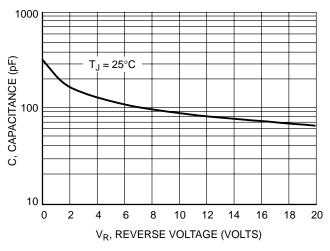
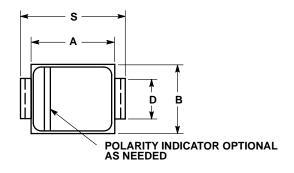


Figure 8. Typical Junction Capacitance

PACKAGE DIMENSIONS

SMA CASE 403D-02 ISSUE A



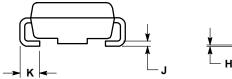
CONTROLLING DIMENSION: INCH. 403D-01 OBSOLETE, NEW STANDARD IS 403D-02.					
	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.160	0.180	4.06	4.57	
В	0.090	0.115	2.29	2.92	
С	0.075	0.095	1.91	2.41	
D	0.050	0.064	1.27	1.63	
Н	0.002	0.006	0.05	0.15	
J	0.006	0.016	0.15	0.41	
Κ	0.030	0.060	0.76	1.52	
S	0.190	0.220	4.83	5.59	

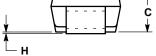
1. DIMENSIONING AND TOLERANCING PER ANSI

NOTES

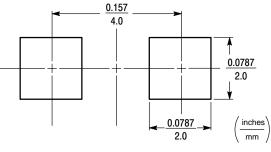
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Y14.5M, 1982.





SOLDERING FOOTPRINT*



SMA FOOTPRINT

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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